In the Claims:

Please cancel claims 1-26 and add claims 27-33 as indicated in the listing of claims to follow.

1-26. (Cancelled)

- 27. (New) A method of manufacturing an interconnect system for conveying a signal between a communication circuit implemented within an integrated circuit and an external node outside the integrated circuit, the method comprising the steps of:
- a. forming an electrostatic discharge (ESD) protection device comprising capacitive impedance within the integrated circuit;
- b. producing a first conductive path comprising inductive impedance extending from the ESD protection device to the external node;
- c. providing a second conductive path comprising inductive impedance extending from the communication circuit to the external node;
- d. selecting a characteristic of a frequency response of the interconnect system from the communication device to the external node;
- e. evaluating a function of the impedances of the first and second conductive paths, the ESD protection device, and the communication circuit to calculate a magnitude of a capacitance at the external node which will substantially optimize the frequency response characteristic selected at step d; and
- f. adjusting the capacitance at the external node to approximate the magnitude calculated at step e.

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- (New) The method in accordance with the claim 27 wherein the function models 28. the interconnect system as a filter formed by interconnected impedances comprising the impedances of the first and second conductive paths, the ESD protection device and the communication circuit and the capacitance at the external node.
- 29. (New) The method in accordance with claim 28 wherein the frequency response characteristic selected at step d is optimized when the magnitude of the capacitance at the external node causes the interconnect system to operate as a Butterworth filter.
- 30. (New) The method in accordance with claim 28 wherein the frequency response characteristic selected at step d is optimized when the magnitude of the capacitance at the external node causes the interconnect system to operate as a Chebyshev filter.
- . 31. (New) The method in accordance with claim 27 wherein the frequency characteristic selected at step d comprises a bandwidth of the interconnect system and is optimized when maximized.
- 32. (New) The method in accordance with claim 27 wherein the frequency characteristic selected at step d comprises a combination of bandwidth and roll-off of the interconnect system.
- 33. (New) The method in accordance with claim 27

wherein the first conductive path comprises a first bond wire extending from the ESD protection device to the external node; and

wherein the second conductive path comprises a second bond wire extending from the communication circuit to the external node.

- 34. (New) The method in accordance with claim 27
- wherein the first and second conductive paths are implemented by a conductive spring contact comprising:
 - a tip contacting the external node,
 - a first conductive leg extending from the ESD protection device to the tip, and
 - a second conductive leg connected from the communication circuit to the tip.
- 35. (New) The method in accordance with claim 27
 - wherein the external node comprises a trace on a printed circuit board, and

wherein the capacitance at the external node is adjusted at step f by forming a via

in the printed circuit board, the via being connected to the trace and adding capacitance to

the external node such that a total capacitance at the external node approximates the

magnitude calculated at step e.